

TF21814

High-Side and Low-Side Gate Driver

Features

- Floating high-side driver in bootstrap operation to 600V
- Drives two N-channel MOSFETs or IGBTs in a half bridge configuration
- 1.9A source / 2.3A sink output current capability
- Outputs tolerant to negative transients
- Wide low side gate driver supply voltage: 10V to 20V
- Logic input (HIN and LIN) 3.3V capability
- Schmitt triggered logic inputs with internal pull down
- Undervoltage lockout for high and low side drivers
- Extended temperature range: -40°C to +125°C

Applications

- Motor Drivers
- Motor Controls
- DC-DC Converters
- Class D Power Amplifiers

Description

The TF21814 is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. TF Semiconductor's high voltage process enables the TF21814's high side to switch to 600V in a bootstrap operation.

The TF21814 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

The TF21814 is offered in PDIP-14 and SOIC-14(N) packages and operate over an extended -40 $^{\circ}$ C to +125 $^{\circ}$ C temperature range.





PDIP-14

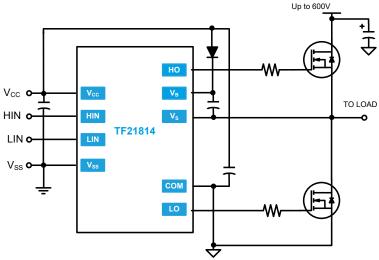
SOIC-14(N)

Ordering Information

Year Year Week Week

PART NUMBER	PACKAGE	PACK / Qty	MARK
			YYWW
TF21814-3BS	PDIP-14	Tube / 25	TF21814
			Lot ID
TF21814-TUU	SOIC-14(N)	Tube / 50	YYWW TF21814
TF21814-TUH	SOIC-14(N)	T&R / 2500	Lot ID

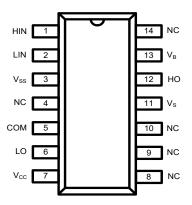
Typical Application



www.tfsemi.com Rev. 1.1

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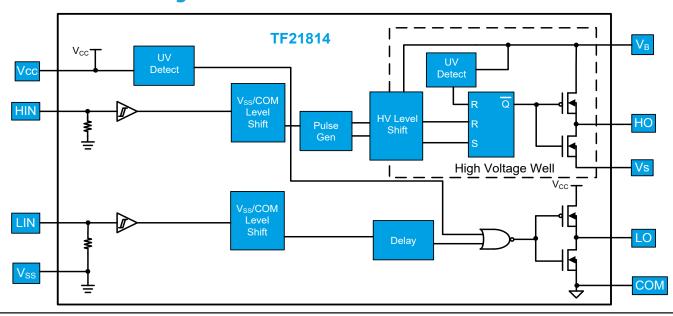


Top View: PDIP-14, SOIC-14

Pin Descriptions

PIN NAME	PIN NUMBER	PIN DESCRIPTION
HIN	1	Logic input for high-side gate driver output, in phase with HO.
LIN	2	Logic input for low-side gate driver output, in phase with LO.
V _{ss}	3	Logic return
NC	4, 8, 9, 10, 14	No Connect
COM	5	Low-side return
LO	6	Low-side gate drive output
V _{cc}	7	Low-side and logic fixed supply
V _s	11	High-side floating supply return
НО	12	High-side gate drive output
V _B	13	High-side floating supply

Functional Block Diagram





Absolute Maximum Ratings (NOTE1)

High-Side and Low-Side Gate Driver

V _B - High side floating supply voltage	0.3V to +624V
V _s - High side floating supply offset voltage	eV_B -24V to V_B +0.3V
V _{HO} -High side floating output voltage	V_{s} -0.3V to V_{B} +0.3V
dV _s /dt-Offset supply voltage transient	50 V/ns
V _{cc} -Low-side fixed supply voltage	0.3V to +24V
V _{ss} - Logic supply offset voltage	V_{cc} -24V to V_{cc} +0.3V
V ₁₀ - Low-side output voltage	0.3V to $V_{cc} + 0.3V$
V_{IN} - Logic input voltage (HIN and LIN)	0.3V to V_{CC}^{cc} +0.3V

NOTE1 Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

P_D - Package power dissipation at $T_A \le 25$ °C SOIC-14PDIP-14	
SOIC-14(N) Thermal Resistance (NOTE2) θ_{J_A} PDIP-14 Thermal Resistance (NOTE2) θ_{J_A}	
T _J - Junction operating temperature T _L - Lead Temperature (soldering, 10 seconds) T _{stg} - Storage temerature	+300°C

NOTE2 Thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Recommended Operating Conditions

Symbol	Parameter	MIN	MAX	Unit
V _B	High side floating supply absolute voltage	V _s + 10	V _s + 20	V
V _s	High side floating supply offset voltage	NOTE3	600	V
V _{HO}	High side floating output voltage	V _s	V _B	V
V _{CC}	Low side fixed supply voltage	10	20	V
V _{LO}	Low side output voltage	СОМ	V _{cc}	V
V _{IN}	Logic input voltage (HIN and LIN)	V _{ss}	5	V
V _{ss}	Logic Ground	-5	+5	V
T _A	Ambient temperature	-40	125	°C

NOTE3 Logic operational for VS of -5V to +600V. Logic state held for VS of -5V to -VBS



DC Electrical Characteristics (NOTE4)

 $V_{\text{BIAS}}(V_{\text{CC}},V_{\text{BS}}) = 15\text{V}, T_{\text{A}} = 25~^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	MIN	TYP	мах	Unit
V _{IH}	Logic "1" input voltage	V _{cc} = 10V to 20V	2.5			
V _{IL}	Logic "0" input voltage	NOTE5			0.8	
V _{OH}	High level output voltage, V _{BIAS} - V _O	$I_{O} = 0A$			1.4	V
V _{OL}	Low level output voltage, V _o	I _o = 20mA			0.2	
I _{LK}	Offset supply leakage current	VB = VS = 600V			50	
I _{BSQ}	Quiescent V _{BS} supply current	V _{IN} = 0V or 5V	20	60	150	μΑ
I _{ccq}	Quiescent V _{CC} supply current	V _{IN} = 0V or 5V	50	120	240	μА
I _{IN+}	Logic "1" input bias current	V _{IN} = 5V		25	60	
I _{IN-}	Logic "0" input bias current	V _{IN} = 0V			5.0	μΑ
V_{BSUV+}	V _{BS} supply under-voltage positive going threshold		8.0	8.9	9.8	
V _{BSUV} -	V _{BS} supply under-voltage negative going threshold		7.4	8.2	9.0	V
$V_{\text{CCUV+}}$	V _{CC} supply under-voltage positive going threshold		8.0	8.9	9.8	
V _{CCUV} -	V _{CC} supply under-voltage negative going threshold		7.4	8.2	9.0	
I _{O+}	Output high short circuit pulsed current	$V_O = 0V$, PW $\leq 10 \mu s$	1.4	1.9		
I ₀₋	Output low short circuit pulsed current	$V_0 = 15V, PW \le 10 \ \mu s$	1.8	2.3		A

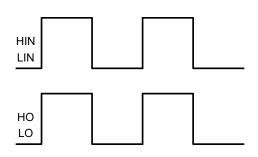
NOTE4 The V_{IIV} V_{TIF} and I_{IN} parameters are applicable to the two logic input pins: LIN and HIN. The V_0 and I_0 parameters are applicable to the respective output pins: HO and LO. **NOTE5** For optimal operation, it is recommended that the input pulse (to HIN and LIN) should have an amplitude of 2.5V minimum with a pulse width of 360ns minimum.



AC Electrical Characteristics $V_{BIAS}(V_{CC}, V_{BS}) = 15V$, $C_L = 1000 pF$, and $T_A = 25 \, ^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Conditions	MIN	TYP	MAX	Unit
t _{on}	Turn-on propogation delay	$V_s = 0V$		180	270	
t _{off}	Turn-off propogation delay	V _s = 0V or 600V		220	330	
t _{DM}	Delay matching, HS & LS turn-on/off				35	
t _r	Turn-on rise time	.,		40	60	ns
t _f	Turn-off fall time	$V_s = 0V$		20	35	

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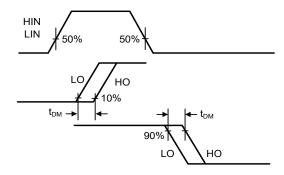


Figure 1. Input / Output Timing Diagram

Figure 2. Delay Matching Waveform Definitions

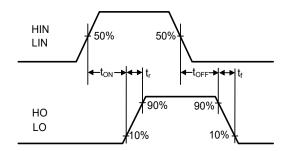


Figure 3. Switching Time Waveform Definitions

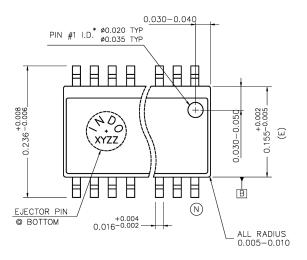


Package Dimensions (SOIC-14 N)

High-Side and Low-Side Gate Driver

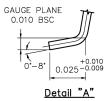
Please contact support@tfsemi.com for package availability.

REV	DESCRIPTION	DATE	BY	REV	DESCRIPTION	DATE	
М	UPDATE FOOT LENGTH MEASUREMENT METHOD	04SEPT06	AGUS S/PE	J	CHANGE FR .035/.045 & FR .045/.055 CHANGE PIN 1 DIA FR #.045 & ADD #.020 TYP	07FEB01	
N	CHANGE COMPANY NAME & LOGO REMOVE "GULL WING " FROM TITLE UPDATE 16L VARIATION	13JUN08	AGUS S/PE	к	UPDATE TABLE, REMOVE CONVENTIONAL MOLD COLUMN	29APR03	H/
				L	UPDATE TABLE, REMOVE MGP MOLD FOR OBN SOIC STANDARD LEAD FRAME	01JUL04	SI

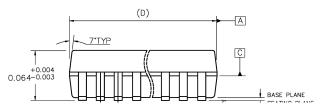


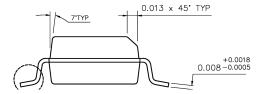
ALL DIMENSIONS ARE IN INCHES UNLESS OTHERWISE NOTE

- 1. "D" & "E" ARE REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSION. MOLD FLASH OR PROTRUSION SHALL NOT EXCEED 6 MILS PER SIDE.
- 2. "N" IS THE NUMBER OF TERMINAL POSITIONS.
- 3. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN 3 MIL! (SEATING PLANE) OUTGOING ASSEMBLY & 4 MILS AFTER TEST.
- 4. THE BOTTOM PACKAGE LEAD SIDE MAY BE BIGGER THAN THE TOP PACKAGE LEAD SIDE BY 4 MILS (2 MILS PER SIDE). BOTTOM PACKAGE DIMENSION SHALL FOLLOW DIMENSION STATED IN THIS DRAWING.
- 5. THE BOTTOM EJECTOR PIN CONTAINS COUNTRY OF ORIGIN "INDO" AND MOLD ID. (REFER TO TABLE FOR OPTION).
- 6. THIS DRAWING CONFORMS TO JEDEC REF. MS-012 REV. E



		٦.	/ADIA T	•	MGP MOLD			
	N	D VARIATION			STAN	IDARD	MAT	RIX
	IN	MIN	NOM	мах	PIN 1 I.D.	EJECT PIN	PIN 1 I.D.	EJECT PIN
	08	0.189	0.193	0.196	N/A		YES	YES
	14	0.337	0.339	0.344	YES	NO	YES	YES
◬	16	0.386	0.390	0.393	N	/A	YES	YES

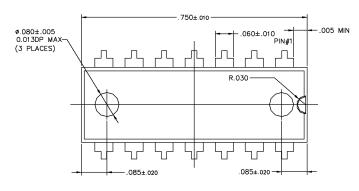


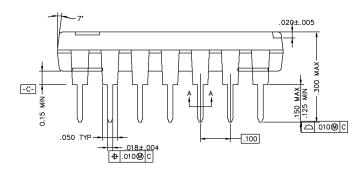


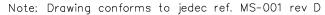
Package Dimensions (PDIP-14)

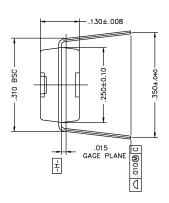
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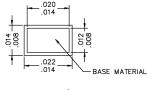
ALL DIMENSIONS ARE IN INCHES UNLESS OTHERWISE NOTED











SECTION A-A}



Rev.	Change	Owner	Date
1.0	First release, Advance info datasheet	Keith Spaulding	11/24/2017
1.1	Add Note 5	Duke Walton	7/30/2019

Important Notice

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